### 1. Features

- Low-voltage and Standard-voltage Operation
  - $-2.7 (V_{CC} = 2.7V \text{ to } 5.5V)$
  - $-1.8 (V_{CC} = 1.8V \text{ to } 5.5V)$
- User-selectable Internal Organization
  - 2K: 256 x 8 or 128 x 16
  - 4K: 512 x 8 or 256 x 16
- Three-wire Serial Interface
- Sequential Read Operation
- 2 MHz Clock Rate (5V)
- Self-timed Write Cycle (10 ms Max)
- High Reliability
  - Endurance: 1 Million Write Cycles
  - Data Retention: 100 Years
- Automotive Devices Available
- 8-lead JEDEC PDIP, 8-lead JEDEC SOIC, 8-lead EIAJ SOIC, 8-lead Ultra Thin mini-MAP (MLP 2x3), 8-lead Ultra Lead Frame Land Grid Array (ULA), 8-lead TSSOP and 8-ball dBGA2 Packages



The AT93C56A/66A provides 2048/4096 bits of serial electrically erasable programmable read-only memory (EEPROM) organized as 128/256 words of 16 bits each (when the ORG pin is connected to VCC) and 256/512 words of 8 bits each (when the ORG pin is tied to ground). The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The AT93C56A/66A is available in space-saving 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead EIAJ SOIC, 8-lead Ultra Thin mini-MAP (MLP 2x3), 8-lead Ultra Lead Frame Land Grid Array (ULA), 8-lead TSSOP, and 8-ball dBGA2 packages.

The AT93C56A/66A is enabled through the Chip Select pin (CS) and accessed via a three-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a read instruction at DI, the address is decoded and the data is clocked out serially on the data output pin DO. The write cycle is completely self-timed and no separate erase cycle is required before write. The write cycle is only enabled when the part is in the Erase/Write Enable State. When CS is brought "high" following the initiation of a write cycle, the DO pin outputs the Ready/Busy status of the part.

The AT93C56A/66A is available in 2.7V to 5.5V and 1.8V to 5.5V versions.



# Three-wire Serial EEPROM

2K (256 x 8 or 128 x 16)

4K (512 x 8 or 256 x 16)

# AT93C56A AT93C66A

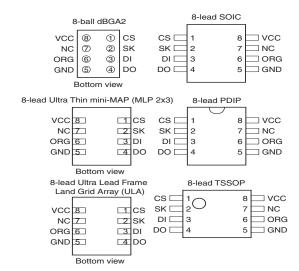
Not Recommended for New Design. Replaced by AT93C56B or AT93C66B.





Table 2-1. Pin Configurations

Pin Name	Function
cs	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
vcc	Power Supply
ORG	Internal Organization
NC	No Connect



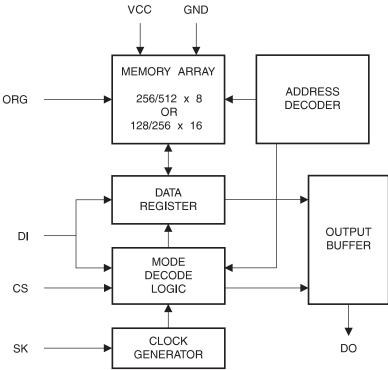
# 3. Absolute Maximum Ratings\*

Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground1.0V to +7.0V
Maximum Operating Voltage 6.25V
DC Output Current

\*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

Figure 3-1. Block Diagram



Note: When the ORG pin is connected to VCC, the x 16 organization is selected. When it is connected to ground, the x 8 organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the x 16 organization is selected.





**Table 3-1.** Pin Capacitance<sup>(Note:)</sup>

Applicable over recommended operating range from  $T_A = 25^{\circ}C$ , f = 1.0 MHz,  $V_{CC} = +5.0$ V (unless otherwise noted)

Symbol	Symbol Test Conditions		Units	Conditions
C <sub>OUT</sub>	Output Capacitance (DO)	5	pF	$V_{OUT} = 0V$
C <sub>IN</sub>	Input Capacitance (CS, SK, DI)	5	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

## Table 3-2.DC Characteristics

Applicable over recommended operating range from:  $T_{AI} = -40^{\circ}C$  to +85°C,  $V_{CC} = +1.8V$  to +5.5V,  $V_{CC} = +1.8V$  to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Unit
V <sub>CC1</sub>	Supply Voltage			1.8		5.5	V
V <sub>CC2</sub>	Supply Voltage			2.7		5.5	V
V <sub>CC3</sub>	Supply Voltage			4.5		5.5	V
	Cupply Current	V 5 0V	READ at 1.0 MHz		0.5	2.0	mA
I <sub>CC</sub>	Supply Current	$V_{CC} = 5.0V$	WRITE at 1.0 MHz		0.5	2.0	mA
I <sub>SB1</sub>	Standby Current	V <sub>CC</sub> = 1.8V	CS = 0V		0.4	1.0	μΑ
I <sub>SB2</sub>	Standby Current	V <sub>CC</sub> = 2.7V	CS = 0V		6.0	10.0	μΑ
I <sub>SB3</sub>	Standby Current	V <sub>CC</sub> = 5.0V	CS = 0V		10.0	15.0	μΑ
I <sub>IL</sub>	Input Leakage	$V_{IN} = 0V \text{ to } V_{CC}$			0.1	3.0	μΑ
I <sub>OL</sub>	Output Leakage	$V_{IN} = 0V \text{ to } V_{CC}$			0.1	3.0	μΑ
V <sub>IL1</sub> (Note:) V <sub>IH1</sub> (Note:)	Input Low Voltage Input High Voltage	$2.7V \le V_{CC} \le 5.5V$		-0.6 2.0		0.8 V <sub>CC</sub> + 1	V
V <sub>IL2</sub> (Note:) V <sub>IH2</sub> (Note:)	Input Low Voltage Input High Voltage	$1.8V \le V_{CC} \le 2.7V$		-0.6 V <sub>CC</sub> x 0.7		V <sub>CC</sub> x 0.3 V <sub>CC</sub> + 1	V
V <sub>OL1</sub>	Output Low Voltage	0.71/ .1/	I <sub>OL</sub> = 2.1 mA			0.4	V
V <sub>OH1</sub>	Output High Voltage	$2.7V \le V_{CC} \le 5.5V$	I <sub>OH</sub> = -0.4 mA	2.4			V
V <sub>OL2</sub>	Output Low Voltage		I <sub>OL</sub> = 0.15 mA			0.2	V
V <sub>OH2</sub>	Output High Voltage	$1.8V \le V_{CC} \le 2.7V$	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> - 0.2			V

Note: 1. V<sub>IL</sub> min and V<sub>IH</sub> max are reference only and are not tested.

Table 3-3. AC Characteristics

Applicable over recommended operating range from  $T_{AI} = -40^{\circ}C$  to + 85°C,  $V_{CC} = As$  Specified, CL = 1 TTL Gate and 100 pF (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
f <sub>SK</sub>	SK Clock Frequency	$\begin{array}{c} 4.5 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \\ 2.7 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \\ 1.8 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \end{array}$		0 0 0		2 1 0.25	MHz
t <sub>SKH</sub>	SK High Time	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$		250 1000			ns
t <sub>SKL</sub>	SK Low Time	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$		250 1000			ns
t <sub>cs</sub>	Minimum CS Low Time	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$		250 1000			ns
t <sub>CSS</sub>	CS Setup Time	Relative to SK	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$	50 200			ns
t <sub>DIS</sub>	DI Setup Time	Relative to SK	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$	100 400			ns
t <sub>CSH</sub>	CS Hold Time	Relative to SK		0			ns
t <sub>DIH</sub>	DI Hold Time	Relative to SK	$\begin{array}{l} 2.7V \leq V_{CC} \leq 5.5V \\ 1.8V \leq V_{CC} \leq 5.5V \end{array}$	100 400			ns
t <sub>PD1</sub>	Output Delay to "1"	AC Test	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$			250 1000	ns
t <sub>PD0</sub>	Output Delay to "0"	AC Test	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$			250 1000	ns
t <sub>SV</sub>	CS to Status Valid	AC Test	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$			250 1000	ns
t <sub>DF</sub>	CS to DO in High Impedance	AC Test CS = V <sub>IL</sub>	$2.7V \le V_{CC} \le 5.5V$ $1.8V \le V_{CC} \le 5.5V$			150 400	ns
t <sub>WP</sub>	Write Cycle Time		1.8V ≤ V <sub>CC</sub> ≤ 5.5V	0.1	3	10	ms
Endurance <sup>(Note:)</sup>	5.0V, 25°C			1M			Write Cycles

Note: 1. This parameter is characterized and is not 100% tested.





Table 3-4. Instruction Set for the AT93C56A and AT93C66A

		Ор	Address		Data		
Instruction	SB	Code	x 8	x 16	x 8	x 16	Comments
READ	1	10	$A_8 - A_0$	$A_7 - A_0$			Reads data stored in memory, at specified address.
EWEN	1	00	11XXXXXXX	11XXXXXX			Write enable must precede all programming modes.
ERASE	1	11	$A_8 - A_0$	$A_7 - A_0$			Erases memory location A <sub>n</sub> – A <sub>0</sub> .
WRITE	1	01	$A_8 - A_0$	$A_7 - A_0$	$D_7 - D_0$	D <sub>15</sub> - D <sub>0</sub>	Writes memory location $A_n - A_0$ .
ERAL	1	00	10XXXXXXX	10XXXXXX			Erases all memory locations. Valid only at $V_{CC} = 4.5V$ to 5.5V.
WRAL	1	00	01XXXXXXX	01XXXXXX	D <sub>7</sub> – D <sub>0</sub>	D <sub>15</sub> – D <sub>0</sub>	Writes all memory locations. Valid only at $V_{CC} = 5.0V \pm 10\%$ and Disable Register cleared.
EWDS	1	00	00XXXXXXX	00XXXXXX			Disables all programming instructions.

Note: The X's in the address field represent don't care values and must be clocked.

## 4. Functional Description

The AT93C56A/66A is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. A valid instruction starts with a rising edge of CS and consists of a Start Bit (logic "1") followed by the appropriate Op Code and the desired memory address location.

**READ (READ):** The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 8- or 16-bit data output string. The AT93C56A/66A supports sequential read operations. The device will automatically increment the internal address pointer and clock out the next memory location as long as Chip Select (CS) is held high. In this case, the dummy bit (logic "0") will not be clocked out between memory locations, thus allowing for a continuous stream of data to be read.

**ERASE/WRITE (EWEN):** To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or V<sub>CC</sub> power is removed from the part.

**ERASE (ERASE):** The Erase instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t<sub>CS</sub>). A logic "1" at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.

**WRITE (WRITE):** The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle  $t_{WP}$  starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A READY/BUSY status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle  $t_{WP}$ .

**ERASE ALL (ERAL):** The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The ERAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

**WRITE ALL (WRAL)**: The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The WRAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

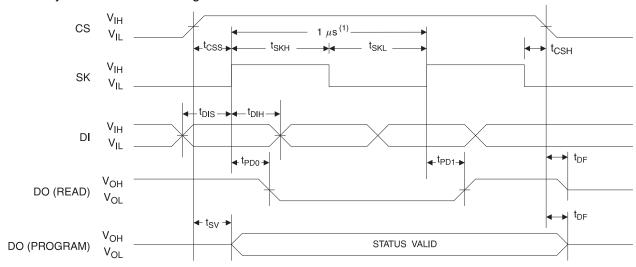
**ERASE/WRITE DISABLE (EWDS):** To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.





# 5. Timing Diagrams

Figure 5-1. Synchronous Data Timing



Note: 1. This is the minimum SK period.

 Table 5-1.
 Organization Key for Timing Diagrams

	AT93C56A (2K)		AT93C6	66A (4K)
I/O	x 8	x 16	x 8	x 16
A <sub>N</sub>	A <sub>8</sub> <sup>(1)</sup>	A <sub>7</sub> <sup>(2)</sup>	A <sub>8</sub>	A <sub>7</sub>
D <sub>N</sub>	D <sub>7</sub>	D <sub>15</sub>	D <sub>7</sub>	D <sub>15</sub>

Notes: 1. A<sub>8</sub> is a DON'T CARE value, but the extra clock is required.

2.  $A_7$  is a DON'T CARE value, but the extra clock is required.



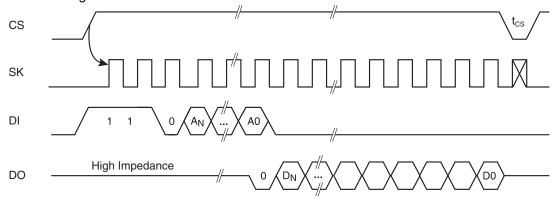


Figure 5-3. EWEN Timing

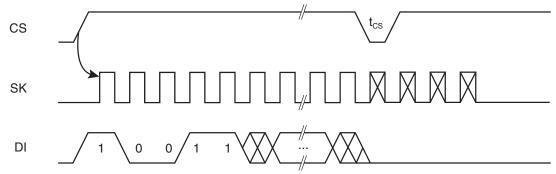


Figure 5-4. EWDS Timing

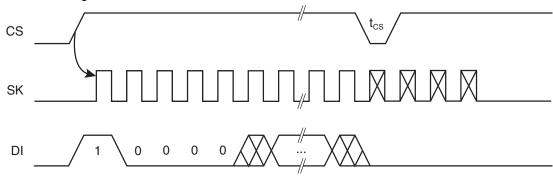


Figure 5-5. WRITE Timing

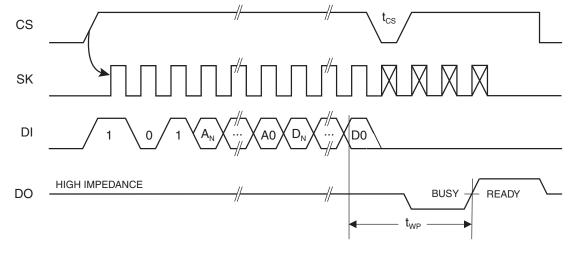
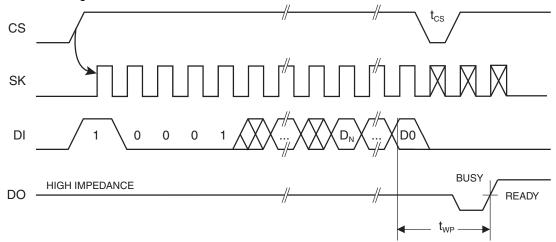




Figure 5-6. WRAL Timing<sup>(1)</sup>



Note: 1. Valid only at  $V_{CC} = 4.5V$  to 5.5V.

Figure 5-7. ERASE Timing

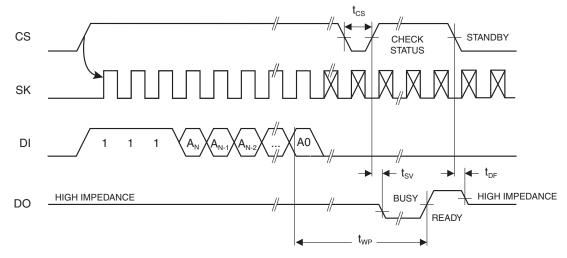
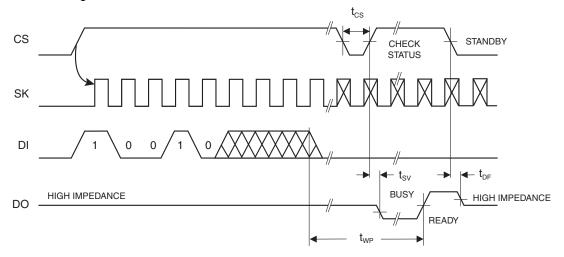


Figure 5-8. ERAL Timing<sup>(1)</sup>



Note: 1. Valid only at  $V_{CC} = 4.5V$  to 5.5V.



# 6. AT93C56A Ordering Information<sup>(1)</sup>

Ordering Code	Package	Operation Range
AT93C56A-10PU-2.7 <sup>(2)</sup>	8P3	
AT93C56A-10PU-1.8 <sup>(2)</sup>	8P3	
AT93C56A-10SU-2.7 <sup>(2)</sup>	8S1	
AT93C56A-10SU-1.8 <sup>(2)</sup>	8S1	
AT93C56AW-10SU-2.7 <sup>(2)</sup>	8S2	
AT93C56AW-10SU-1.8 <sup>(2)</sup>	8S2	Lead-free/Halogen-free/ Industrial Temperature
AT93C56A-10TU-2.7 <sup>(2)</sup>	8A2	(–40°C to 85°C)
AT93C56A-10TU-1.8 <sup>(2)</sup>	8A2	(-40 0 10 65 0)
AT93C56AU3-10UU-1.8 <sup>(2)</sup>	8U3-1	
AT93C56AD3-10DH-1.8 <sup>(3)</sup>	8D3	
AT93C56AY1-10YU-1.8 <sup>(2)</sup> (Not recommended for new design)	8Y1	
AT93C56AY6-10YH-1.8 <sup>(3)</sup>	8Y6	
AT93C56A-W1.8-11 <sup>(4)</sup>	Die Sales	Industrial Temperature (-40°C to 85°C)

Notes: 1. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics table.

- 2. "U" designates Green package + RoHS compliant.
- 3. "H" designates Green package + RoHS compliant, with NiPdAu Lead Finish.
- 4. Available in waffle pack and wafer form; order as SL788 for inkless wafer form. Bumped die available upon request. Please contact Serial Marketing.

	Package Type				
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)				
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)				
8S2	8-lead, 0.200" Wide, Plastic Gull Wing Small Outline (EIAJ SOIC)				
8A2	8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)				
8U3-1	8-ball, die Ball Grid Array Package (dBGA2)				
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)				
8Y6	8-lead, 2.00 mm x 3.00 mm Body, 0.50 mm Pitch, Ultra Thin Mini-MAP, Dual No Lead package (DFN), (MLP 2x3 mm)				
8D3	8-lead, 1.80 mm x 2.20 mm Body, Ultra Lead Frame Land Grid Array (ULA)				
	Options				
-2.7	Low-voltage (2.7V to 5.5V)				
-1.8	Low-voltage (1.8V to 5.5V)				

# 7. AT93C66A Ordering Information<sup>(1)</sup>

Ordering Code	Package	Operation Range
AT93C66A-10PU-2.7 <sup>(2)</sup>	8P3	
AT93C66A-10PU-1.8 <sup>(2)</sup>	8P3	
AT93C66A-10SU-2.7 <sup>(2)</sup>	8S1	
AT93C66A-10SU-1.8 <sup>(2)</sup>	8S1	
AT93C66AW-10SU-2.7 <sup>(2)</sup>	8S2	
AT93C66AW-10SU-1.8 <sup>(2)</sup>	8S2	Lead-free/Halogen-free/ Industrial Temperature
AT93C66A-10TU-2.7 <sup>(2)</sup>	8A2	(–40°C to 85°C)
AT93C66A-10TU-1.8 <sup>(2)</sup>	8A2	(-40 0 10 65 0)
AT93C66AU3-10UU-1.8 <sup>(2)</sup>	8U3-1	
AT93C66AD3-10DH-1.8 <sup>(3)</sup>	8D3	
AT93C66AY1-10YU-1.8 <sup>(2)</sup> (Not recommended for new design)	8Y1	
AT93C66AY6-10YH-1.8 <sup>(3)</sup>	8Y6	
AT93C66A-W1.8-11 <sup>(4)</sup>	Die Sale	Industrial Temperature
ATOCOONTYTICT	Die Sale	(-40°C to 85°C)

Notes: 1. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics table.

- 2. "U" designates Green package + RoHS compliant.
- 3. "H" designates Green package + RoHS compliant, with NiPdAu Lead Finish.
- 4. Available in waffle pack and wafer form; order as SL788 for inkless wafer form. Bumped die available upon request. Please contact Serial EEPROM Marketing.

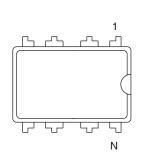
	Package Type					
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)					
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)					
8S2	8-lead, 0.200" Wide, Plastic Gull Wing Small Outline (EIAJ SOIC)					
8A2	8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)					
8U3-1	8-ball, die Ball Grid Array Package (dBGA2)					
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)					
8Y6	8-lead, 2.00 mm x 3.00 mm Body, 0.50 mm Pitch, Ultra Thin Mini-MAP, Dual No Lead package (DFN), (MLP 2x3 mm)					
8D3	8-lead, 1.80 mm x 2.20 mm Body, Ultra Lead Frame Land Grid Array (ULA)					
	Options					
-2.7	Low-voltage (2.7V to 5.5V)					
-1.8	Low-voltage (1.8V to 5.5V)					



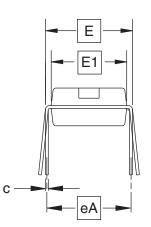


# 8. Packaging Information

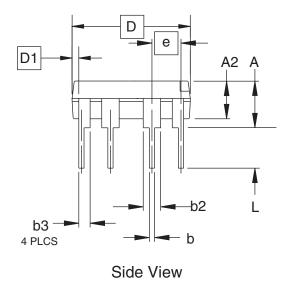
## 8.1 8P3 - PDIP



Top View



**End View** 



### **COMMON DIMENSIONS**

(Unit of Measure = inches)

SYMBOL	MIN	NOM	MAX	NOTE
Α			0.210	2
A2	0.115	0.130	0.195	
b	0.014	0.018	0.022	5
b2	0.045	0.060	0.070	6
b3	0.030	0.039	0.045	6
С	0.008	0.010	0.014	
D	0.355	0.365	0.400	3
D1	0.005			3
Е	0.300	0.310	0.325	4
E1	0.240	0.250	0.280	3
е	(			
eA	(	4		
L	0.115	0.150	2	

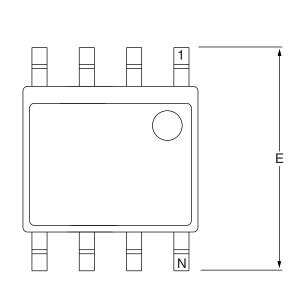
Notes:

- 1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
- 2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
- 3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
- 4. E and eA measured with the leads constrained to be perpendicular to datum.
- 5. Pointed or rounded lead tips are preferred to ease insertion.
- 6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

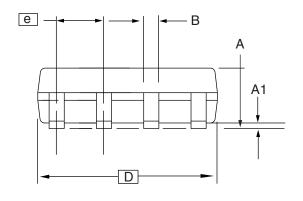
01/09/02

I _		TITLE	DRAWING NO.	REV.
A	2325 Orchard Parkway San Jose, CA 95131	<b>8P3</b> , 8-lead, 0.300" Wide Body, Plastic Dual In-line Package (PDIP)	8P3	В

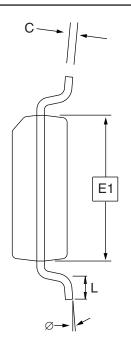
## 8.2 8S1 - JEDEC SOIC



Top View



Side View



**End View** 

## COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
А	1.35	-	1.75	
A1	0.10	-	0.25	
b	0.31	_	0.51	
С	0.17	-	0.25	
D	4.80	-	5.00	
E1	3.81	_	3.99	
Е	5.79	_	6.20	
е	1.27 BSC			
L	0.40	_	1.27	
Ø	0°	_	8°	

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

10/7/03



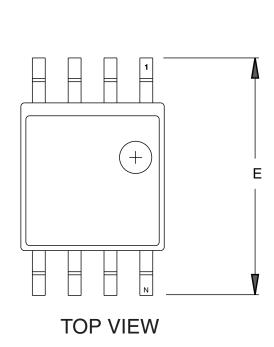
1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 **TITLE 8S1**, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)

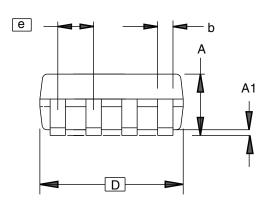
BS1 REV.



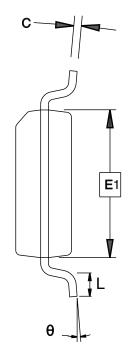


#### 8.3 8S2 - EIAJ SOIC





SIDE VIEW



## **END VIEW**

# **COMMON DIMENSIONS**

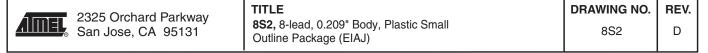
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	1.70		2.16	
A1	0.05		0.25	
b	0.35		0.48	5
С	0.15		0.35	5
D	5.13		5.35	
E1	5.18		5.40	2, 3
Е	7.70		8.26	
L	0.51		0.85	
θ	0°		8°	
е		1.27 BSC		4

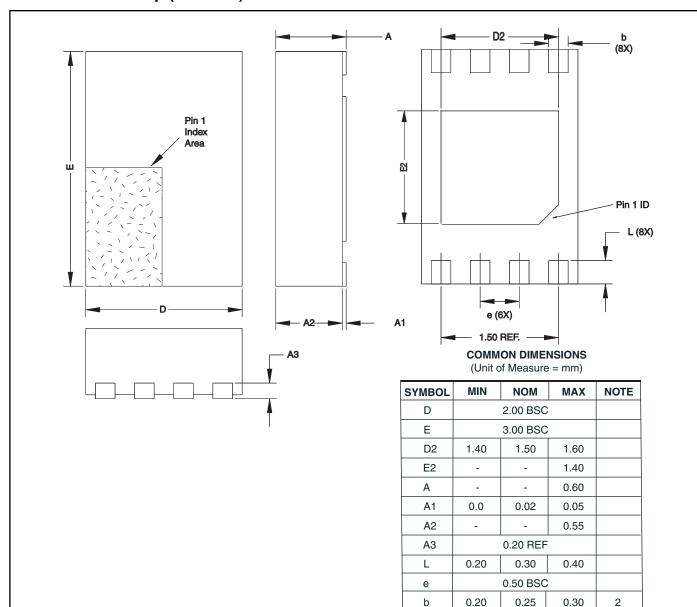
Notes: 1. This drawing is for general information only; refer to EIAJ Drawing EDR-7320 for additional information.

- 2. Mismatch of the upper and lower dies and resin burrs aren't included.
- 3. It is recommended that upper and lower cavities be equal. If they are different, the larger dimension shall be regarded.
- 4. Determines the true geometric position.
- 5. Values b,C apply to plated terminal. The standard thickness of the plating layer shall measure between 0.007 to .021 mm.

04/07/06



## 8.4 8Y6 – MiniMap (MLP 2x3)



Notes:

- This drawing is for general information only. Refer to JEDEC Drawing MO-229, for proper dimensions, tolerances, datums, etc.
- 2. Dimension b applies to metallized terminal and is measured between 0.15 mm and 0.30 mm from the terminal tip. If the terminal has the optional radius on the other end of the terminal, the dimension should not be measured in that radius area.
- 3. Soldering the large thermal pad is optional, but not recommended. No electrical connection is accomplished to the device through this pad, so if soldered it should be tied to ground

11/21/08 D. | **REV**.

Ε

DRAWING NO.

8Y6



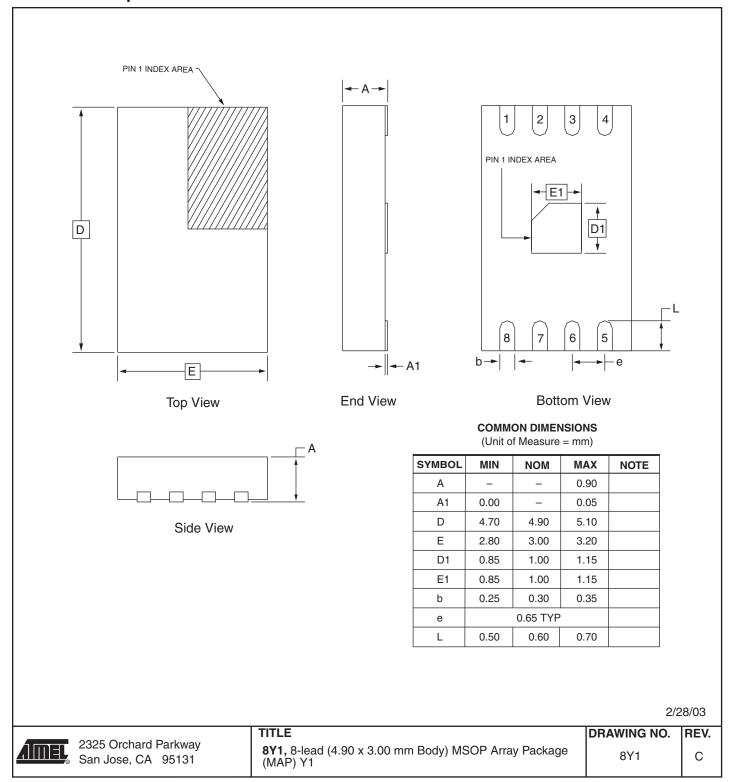
Package Drawing Contact: packagedrawings@atmel.com

TITLE	GPC
8Y6, 8-lead 2.0x3.0 mm Body, 0.50 mm Pitch,	
UltraThin Mini-MAP, Dual No Lead Package	YNZ
(Sawn)(UDFN)	

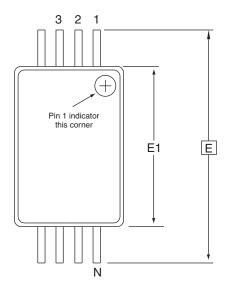




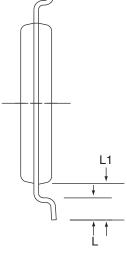
# 8.5 8Y1 – Map



#### 8.6 **8A2 - TSSOP**



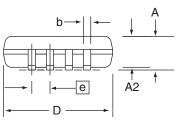
Top View



**End View** 

#### **COMMON DIMENSIONS**

(Unit of Measure = mm)



	iew

SYMBOL	MIN	NOM	MAX	NOTE
D	2.90	3.00	3.10	2, 5
Е		6.40 BSC		
E1	4.30	4.40	4.50	3, 5
Α	_	_	1.20	
A2	0.80	1.00	1.05	
b	0.19	_	0.30	4
е	0.65 BSC			
L	0.45	0.60	0.75	
L1	1.00 REF			

- Notes: 1. This drawing is for general information only. Refer to JEDEC Drawing MO-153, Variation AA, for proper dimensions, tolerances, datums, etc.
  - 2. Dimension D does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15 mm (0.006 in) per side.
  - 3. Dimension E1 does not include inter-lead Flash or protrusions. Inter-lead Flash and protrusions shall not exceed 0.25 mm (0.010 in) per side.
  - 4. Dimension b does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the b dimension at maximum material condition. Dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and adjacent lead is 0.07 mm.
  - 5. Dimension D and E1 to be determined at Datum Plane H.

5/30/02



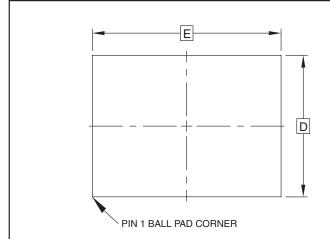
2325 Orchard Parkway San Jose, CA 95131

TITLE 8A2, 8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP) DRAWING NO. REV. 8A2 В

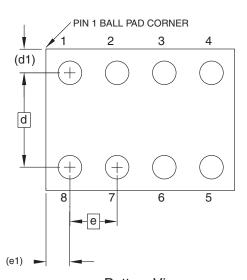




#### 8.7 8U3-1 - dBGA2

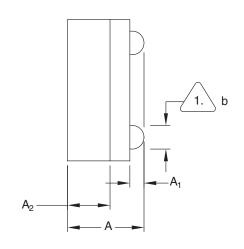


Top View



**Bottom View** 8 Solder Balls

- This drawing is for general information only.
   Dimension 'b' is measured at maximum solder ball diameter



Side View

#### COMMON DIMENSIONS (Unit of Measure = mm)

	`			
SYMBOL	MIN	NOM	MAX	NOTE
Α	0.713	0.79	0.85	
A1	0.09	0.14	0.19	
A2	0.40	0.45	0.50	
b	0.20	0.25	0.30	2
D	1.50 BSC			
Е	2.00 BSC			
е	0.50 BSC			
e1	0.25 REF			
d	1.00 BSC			
d1	0.25 REF			

5/3/05

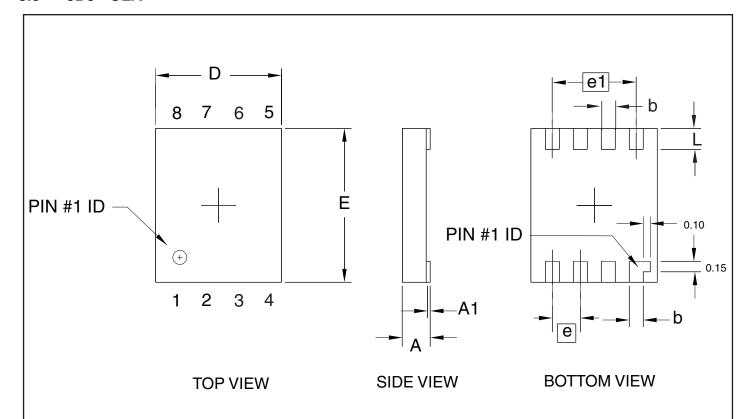
1150E Cheyenne Mt. Blvd Colorado Springs, CO 80906 TITLE

8U3-1,8-ball, 1.50 x 2.00 mm Body, 0.50 mm pitch, Small Die Ball Grid Array Package (dBGA2)

DRAWING NO. PO8U3-1

REV. b

#### 8.8 8D3 - ULA



### **COMMON DIMENSIONS**

(Unit of Measure = mm)

	(		,	
SYMBOL	MIN	NOM	MAX	NOTE
А	_	_	0.40	
A1	0.00	_	0.05	
D	1.70	1.80	1.90	
Е	2.10	2.20	2.30	
b	0.15	0.20	0.25	
е		0.40 TYP		
e1		1.20 REF		
L	0.25	0.30	0.35	

11/15/05

**AIMEL** 

1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 TITLE

**8D3**, 8-lead (1.80 x 2.20 mm Body) Ultra Leadframe Land Grid Array (ULLGA) D3

DRAWING NO. REV. 8D3

0





# 9. Revision History

Revision No.	Date	Comments
3378O	07/2012	Not recommended for new design. Use AT93C56B/66B.
3378O	11/2009	Added 8S2 package drawing
3378N	1/2009	Updated 8Y6 package drawing
3378M	7/2008	Updated Ordering Codes
3378L	11/2007	Updated to new template Added ULA package offering
3378K	12/2006	Removed DC/Don't Connect and replaced with NC/No Conenct Adjusted size of Block diagram on pg. 2 Made all diagrams on pages 6-9 consistently the same size Corrected 8U3-1



### Headquarters

Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131 USA

Tel: 1(408) 441-0311 Fax: 1(408) 487-2600

#### International

Atmel Asia

Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimshatsui East Kowloon Hong Kong

Tel: (852) 2721-9778 Fax: (852) 2722-1369 Atmel Europe

Le Krebs 8, Rue Jean-Pierre Timbaud BP 309 78054 Saint-Quentin-en-

Yvelines Cedex France

Tel: (33) 1-30-60-70-00 Fax: (33) 1-30-60-71-11

Atmel Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan

Tel: (81) 3-3523-3551 Fax: (81) 3-3523-7581

#### **Product Contact**

Web Site

www.atmel.com

Technical Support

s\_eeprom@atmel.com

Sales Contact

www.atmel.com/contacts

Literature Requests

www.atmel.com/literature

Disclaimer: The information in this document is provided in connection with Atmel products. No license, express or implied, by estoppel or otherwise, to any intellectual property right is granted by this document or in connection with the sale of Atmel products. EXCEPT AS SET FORTH IN ATMEL'S TERMS AND CONDITIONS OF SALE LOCATED ON ATMEL'S WEB SITE, ATMEL ASSUMES NO LIABILITY WHATSOEVER AND DISCLAIMS ANY EXPRESS, IMPLIED OR STATUTORY WARRANTY RELATING TO ITS PRODUCTS INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTY OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT. IN NO EVENT SHALL ATMEL BE LIABLE FOR ANY DIRECT, INDIRECT, CONSEQUENTIAL, PUNITIVE, SPECIAL OR INCIDENTAL DAMAGES (INCLUDING, WITHOUT LIMITATION, DAMAGES FOR LOSS OF PROFITS, BUSINESS INTERRUPTION, OR LOSS OF INFORMATION) ARISING OUT OF THE USE OR INABILITY TO USE THIS DOCUMENT, EVEN IF ATMEL HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES. Atmel makes no representations or warranties with respect to the accuracy or completeness of the contents of this document and reserves the right to make changes to specifications and product descriptions at any time without notice. Atmel does not make any commitment to update the information contained herein. Unless specifically provided otherwise, Atmel products are not suitable for, and shall not be used in, automotive applications. Atmel's products are not intended, authorized, or warranted for use as components in applications intended to support or sustain life.

© 2009 Atmel Corporation. All rights reserved. Atmel<sup>®</sup>, Atmel logo and combinations thereof, and others, are registered trademarks or trademarks of Atmel Corporation or its subsidiaries. Other terms and product names may be trademarks of others.